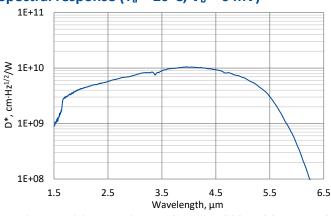


PVAS-2TE-5-0.1×0.1-T08-wAl₂O₃-70 - ENGINEERING SAMPLE

Type II superlattice, two-stage thermoelectrically cooled, photovoltaic detector

 $\textbf{PVAS-2TE-5-0.1} \times \textbf{0.1-T08-wAl}_2\textbf{0}_3\textbf{-70} \text{ is a Type II superlattice two-stage thermoelectrically cooled IR photovoltaic detector, with excellent parameters. } 3^{\circ} \text{ wedged sapphire window } (\text{wAl}_2\textbf{0}_3) \text{ prevents unwanted interference effects. This detector does not contain } 1 \times 10^{-10} \text{ m}^{-1} \text{ m}^{$ mercury or cadmium and is compliant with the RoHS Directive.

Spectral response ($T_a = 20$ °C, $V_b = 0$ mV)





Exemplary spectral detectivity, the spectral response of delivered devices may differ.

Specification ($T_a = 20$ °C, $V_b = 0$ mV)

| Parameter | Detector type |
|--|--|
| | PVAS-2TE-5-0.1×0.1-TO8-wAl ₂ O ₃ -70 |
| Active element material | epitaxial superlattice heterostructure |
| Cut-on wavelength λ _{cut-on} (10%), μm | 1.7±0.2 |
| Peak wavelength λ _{peak} , μm | 4.0±0.3 |
| Cut-off wavelength $\lambda_{\text{cut-off}}$ (10%), μ m | 5.8±0.2 |
| Detectivity D*(λ _{peak}), cm·Hz ^{1/2} /W | ~9.0×10 ⁹ |
| Current responsivity $R_i(\lambda_{peak})$, A/W | ~1.4 |
| Time constant т, ns | ~4 |
| Resistance R, Ω | ~5k |
| Active element temperature T _{det} , K | ~230 |
| Active area A, mm×mm | 0.1×0.1 |
| Package | TO8 |
| Acceptance angle Φ | ~70° |
| Window | wAl_2O_3 |

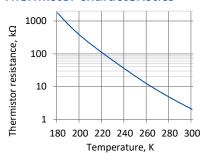
Features

- Wide spectral range from 1.7 to 5.8 µm
- High responsivity
- **Excellent linearity**
- No bias required
- No 1/f noise
- Environmentally friendly

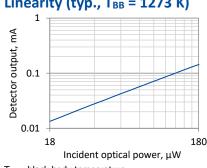
Two-stage thermoelectric cooler parameters

| Parameter | Value |
|----------------------|-------|
| T _{det} , K | ~230 |
| V _{max} , V | 1.3 |
| I _{max} , A | 1.2 |
| Q _{max} , W | 0.36 |

Thermistor characteristics



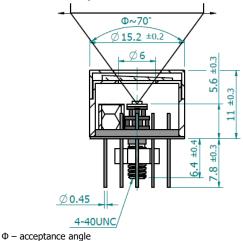
Linearity (typ., $T_{BB} = 1273 \text{ K}$)

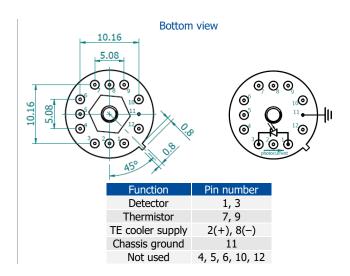


T_{BB} – black body temperature









Dedicated preamplifiers







programmable PIP



standard MIP



small SIP-TO8

Precautions for use and storage

- Heatsink with thermal resistance of ~2 K/W is necessary to dissipate heat generated by 2TE cooler.
- Operation in 10% to 80% humidity and -20°C to 30°C ambient temperature.
- Beam power limitations:
 - irradiance with CW or single pulse longer than 1 μs irradiance on the apparent optical active area must not exceed 100 W/cm²,
 - irradiance of the pulse shorter than 1 μs must not exceed 1 MW/cm².
- Storage in dark place with 10% to 90% humidity and -20°C to 50°C ambient temperature.